

N. T. PELEKANOS

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CAREER OBJECTIVE:

Research, development and education in the fields of **Nanophotonics & Optoelectronics**.

EDUCATION:

Ph.D. in Physics, Brown University, Providence (RI), USA, July 1991
Title of dissertation: "Exciton-phonon interaction effects in II-VI semiconductor heterostructures".
Scientific advisor: Professor A. V. Nurmikko
M.Sc. in Physics, Brown University, Providence (RI), USA, May 1987
B.Sc. in Physics, University of Athens, Athens, Greece, July 1985

PROFESSIONAL EXPERIENCE:

- 2003- today:** **Professor**, Materials Science & Technology Department, University of Crete, and Senior Researcher at the Microelectronics Research Group of the Institute of Electronic Structure & Laser/FORTH, Heraklion, Greece, leading research in the field of Semiconductor Nanotechnology with emphasis on Optoelectronic applications.
- 2001-2003:** **Senior Researcher**, Microelectronics Research Group, Institute of Electronic Structure & Laser/FORTH, Heraklion, Greece, demonstrating tunable laser diodes and LEDs and studying semiconductor quantum dots.
- 1994-2001:** **Research Engineer** (permanent position), Laboratory of Semiconductor Physics, Department of Fundamental Research on Condensed Matter, Commissariat à l'Energie Atomique, Grenoble, France, performing optical characterization of III-nitride hetero/nano-structures and experimenting on all-optical piezoelectric modulators.
- 1993-1994:** **Postdoctoral Researcher**, Ultrafast Spectroscopy Group, Max-Planck-Institute for Solid State Research, Stuttgart, Germany, demonstrating an all-optical quantum well- based spatial light modulator for parallel image processing and carrying out ultrafast spectroscopy on II-VI heterostructures.
- 1992-1993:** **Research Engineer**, Optical Interconnection Group, Centre National d'Etudes des Télécommunications, France-Telecom, Lannion, France, developing photorefractive quantum well devices for optical switching in telecommunications.
- 1991-1992:** **Postdoctoral Researcher**, Laboratory of Semiconductor Physics, Department of Fundamental Research on Condensed Matter, Commissariat à l'Energie Atomique, Grenoble, France, studying optical properties of II-VI semiconductor heterostructures.

RESEARCH INTERESTS:

- a) Quantum dot-based high temperature sources of single and entangled photons.
- b) Polariton lasing and parametric scattering at room temperature.
- c) Next generation solar cells based on halide perovskites and III-V semiconductor nanostructures.
- d) 2D materials for optoelectronic applications.

ACHIEVEMENTS:

RESEARCH

- A total of 249 publications, including:
 - 7 patents
 - 56 publications in peer-reviewed journals
 - 64 conference papers in peer-reviewed journals
 - 2 papers in special issues
 - 1 book chapter
 - 119 abstracts in conference proceedings.
- About 3150 citations and a corresponding H-factor of 29.
- 18 invited talks in conferences/workshops and 15 invited talks in academic institutions.
- Coordination/participation in 24 national, 6 European, 1 industrial, and 4 bilateral research contracts, whose total estimated budget for the home institutions is over 4 million Euros.
- Supervised 5 post-docs, 10 PhD and 12 MSc theses. Currently supervising 3 PhD candidates.
- Evaluation expert for European and national research programs (Greece, France, Israel).
- Referee in various academic journals (PRL, PRB, PRAppI, APL, JAP, ACS Photonics, Sci. Rep.).
- Organized/co-organized 9 conferences/workshops.
- Participated in numerous electoral committees for professor/researcher positions.

ADMINISTRATIVE WORK

At the Department level:

- Chairman, 2007-2009.
- Vice-Chairman, 2004-2007.
- Director of undergraduate studies, 2004-2010.
- Evaluation Committee, 2012-2016.

At the University level:

- Director of Technical Council, 2017-now.
- Member of Research Committee, 2012-2014.
- Responsible for the Final Reception Protocol of the new University buildings in Voutes, 2014.
- Member of New Technologies Committee, 2016-2018.

At the Region level:

- Member of the Regional Research and Innovation Council of Crete, 2017-now.

AWARDS

- Chaire d'Excellence LANEF, funded by the French government, for a project entitled "*Nanowire Innovative Solar Cells*", 2014-2017.
- Solar Innovation 2010 Award, by the French Atomic Energy Commission for a proposal on "*III-V Nanowires for Next Generation Photovoltaics*", 2011-2013.
- Alexander von Humboldt-Stiftung fellowship, 1993-1994.
- Bourse du Ministère des Affaires Etrangères, 1991-1992.

DETAILED RECORD:

PATENTS:

7. Growth of nitride semiconductor heterostructures including Indium Aluminium Gallium Nitride alloy layers by Molecular Beam Epitaxy with RF-plasma source,

A. Georgakilas, N. Pelekanos, E. Dimakis, FORTH, Application for Greek Patent, Ref. N. 20020100376 (9-8-2002).

6. Optical semiconductor device with resonant cavity tunable in wavelength, application to modulation of light intensity,

V. Ortiz, N. T. Pelekanos, CEA/Grenoble, French Patent application Nr. 99 08783, filed July 7, 1999. Extended to the USA in June 2000, where it was granted as US 6,396,083 B1 (DoP: May 28, 2002).

5. Semiconductor laser with tunable gain spectrum,

N. T. Pelekanos, V. Ortiz, G. Mula, CEA/Grenoble, French Patent application Nr. 98 12558, filed Oct. 7, 1998. Extended to USA in 1999, where it was granted as US 6,353,624 B1 (DoP: March 5, 2002).

4. An educational crossword game,

J. Jorge Pelekanos, N. T. Pelekanos, U.S. Patent application, filed January 1996.

3. Optically-controlled light modulator device,

N. T. Pelekanos, European Patent Application #94107158.1, filed in 1994. Extended to USA in 1995, where it was granted as US 5,698,863 (DoP: Dec.16, 1997).

2. Ultrafast photorefractive cell operating at 1.55 μ m,

B. Deveaud, N. T. Pelekanos, B. Lambert, France Telecom, French Patent Nr. 9313718, filed in 1993, extended in USA in 1994.

1. All-optical photodiffractive device based on GaAs/AlAs quantum filters,

N. T. Pelekanos, B. Deveaud, P. Gravey, J. M. Gérard, France Telecom, French Patent Nr. 9314789, filed in 1993, extended in USA in 1994.

FUNDING:

European:

-Participation in European contract entitled CLERMONT 4, FP7-PEOPLE-ITN-235114, "*Exciton-Polaritons in microcavities: physics and devices*" (2009-2013). FORTH budget 314,570 €.

-Participation in European contract entitled ICARUS, FP7-PEOPLE-ITN-237900, "*Hybrid organic-inorganic nanostructures for photonics and optoelectronics*" (2009-2013). FORTH budget ~410,000€.

-Matching Funds: I have managed 108,572 € since 2001.

-Principal contractor and team coordinator in European contract entitled GaNano, NMP-2002-505641-1, "*New Generation of GaN-based sensor arrays for nano- and pico-fluidic systems for fast and reliable biomedical testing*" (2004-2006). FORTH budget 364,000€.

-Coordination of European contract entitled QN-Laser II, IST-2001-38982, "*Quaternary nitride low-threshold laser II*" (2003). FORTH budget 68,000€.

-Coordination of European contract entitled TUNE-Laser, IST-2000-31028, "*Tunable laser diode based on the Stark effect*" (2001-2002). FORTH budget 100,000€.

-Coordination of European contract entitled QN-Laser, IST-2000-26464, "*Quaternary nitride low-threshold laser*" (2001-2002). FORTH budget 100,000€.

National:

-Coordination of EDBM103 project entitled "*Nanophotonic semiconductor sources of single and entangled photons*", funded by the Greek government (2020-2021). Budget 37,000 €.

-Supervision of Doctoral Fellowship of E. Amargianitakis funded by the Stavros Niarhos Foundation, entitled "*Entangled photons in GaN Polariton Lasers*" (2019-2020). Budget 9,000 €.

-Coordination of RIS3Crete project "NANOTANDEM" funded by the Region of Crete, on "*High performance Perovskite/III-V semiconductor Nanostructure Tandem Solar Cells*" (2019-2022). Budget 212,500 €.

-Participation in Infrastructures project "INNOVATION-EL", co-financed by Greece and the European Regional Development Fund (2018-2021). Budget 25,875 €.

-Supervision of Doctoral Fellowship of G. Thyris funded by the Stavros Niarhos Foundation, entitled "*High temperature single photon emitters based on InAs piezoelectric quantum dots*" (2018-2019). Budget 11,500 €.

-Participation in KRHPIS II project “AENAO”, co-financed by Greece and the European Regional Development Fund on “Materials and Processes for Energy and Environment Applications” (2017-2020). Budget 16,000 €.

-Supervision of Doctoral Fellowship of E. Amargianitakis funded by the Hellenic Foundation for Research and Innovation, entitled “*Nitride Polariton Lasers*” (2017-2019). Budget 23,400 €.

-Coordination of LANEF Chair of Excellence 2014 project, funded by the French government, entitled “*Nanowire Innovative Solar Cells*” (2014-2017). Total budget ~300,000 €.

-Coordination of ARISTEIA II project “NILES” funded by the Greek government, on “*Nanowire Innovative Light Emitting devices and Solar cells*” (2014-2015). Total budget 245,000 €.

-Coordination of THALES project “NANOPHOS” funded by the Greek government, on “*Nanophotonic Semiconductor Devices*” (2012-2015). Total budget 540,000 €

-Coordination of Solar Innovation 2010 Award project funded by the French government on “*III-V Nanowires for Next-generation Photovoltaics*” (2011-2013). Total budget ~250,000 €.

-Coordination of HRAKLEITOS II project funded by the Greek government, on “*Photonic Devices of Piezoelectric Quantum Dots*” (2010-2014). Total budget 45,000 €.

-Συμμετοχή στο Πρόγραμμα Πόλου Καινοτομίας Κρήτης, 2007-2008, πάνω σε χαρακτηρισμό ημιαγωγικού υλικού για χημικούς αισθητήρες. Budget 16,000 €.

-University grant from Public Investments 2006, for the purchase of a “*Femtosecond Ti:Sapphire laser system*” (2006-2007). Total budget 250,000 €.

-Coordination of PENED 2003 project funded by the Greek government, on “*Tunable wavelength semiconductor lasers*” (2006-2009). Total budget 138,480 €.

-Participation in PENED 2003 project funded by the Greek Research Council, on “*Strong coupling in GaN-based microcavities for polariton devices*” (2005-2008). Total budget 80,000 €.

-Participation in PYTHAGORAS project funded by the Greek government, on “*Exploitation of strong light-matter coupling in organic microcavities for optoelectronic devices*” (2005-2006). Total budget 80,000 €.

-Participation in PYTHAGORAS project funded the Greek government, on “*Growth and Properties on Novel III-V semiconductor heterostructures and nanostructures*” (2004-2006). Total budget 80,000 €.

-Coordination of PENED 2001 project funded by the Greek government, on “*UV-emitters*” (2003-2006). Total budget 205,430 €.

-Participation in Program of Excellence (Πρόγραμμα Αριστείας), granted to FORTH/IESL by the Greek government (2002-2006). Personal budget for building a UV micro-photoluminescence setup 100,000 €.

-Participation in program EPEAEK, funded by the Greek government in order to support the Graduate Program on Micro- and Optoelectronics of the Physics Department of the University of Crete for the period 2002-2004.

-Participation in Contrat-Région funded by the French government, on “*Cubic nitride light emitting diodes*” (1998-1999).

-Participation in Contrat-Région funded by the French government, on “*Nitride nanostructures: growth and characterisation*” (1998-1999).

-Participation in PENED with National Technical University of Athens funded by the Greek government, on “*Hot electron-acceptor luminescence as a probe of dynamic relaxation processes in semiconductor heterostructures*” (1997-1999).

Bilateral:

-Coordination of Contrat Franco-Hellenique funded by the Ministries of Foreign Affairs of France and Greece, on “*Piezoelectric quantum dots for photonic applications*” (2006-2008).

-Coordination of IKYDA exchange program between Greece and Germany (Technical University of Ilmenau), funded by IKY, on “*Study for enhancing the performance of GaN-based UV photodiodes and lasers*” (2004-2006).

-Coordination of Contrat Franco-Hellenique funded by the Ministries of Foreign Affairs of France and Greece, on “*Epitaxial growth and fabrication of quaternary nitride lasers with enhanced performance in the UV*” (2003-2005).

-Coordination of Contrat Franco-Hellenique funded by the Ministries of Foreign Affairs of France and Greece, on “*Comparative study of hexagonal and cubic GaN heterostructures*” (2000-2001).

Industrial:

-Participation in research contract funded by France Telecom, on “*Photorefractive quantum wells for optical interconnects*” (1993-1995).

EDUCATIONAL WORK:

Teaching:

-Course on “*Introduction in Semiconductors and Microelectronic/Optoelectronic Devices*” in the 2nd year of the undergraduate program of the Materials Science and Technology Department of Univ. of Crete (spring semester 2020).

-Course on “*Electromagnetism and Optics*” in the 3rd year of the undergraduate program of the Materials Science and Technology Department of Univ. of Crete (fall semester 2003-2018).

-Course on “*Principles of Semiconductor Physics*” in the 4th year of the undergraduate program of the Materials Science and Technology Department of Univ. of Crete (spring semester 2009-2018, fall semester 2019).

-Course on “*Semiconductor Optoelectronic Devices*” in the Microelectronics/Optoelectronics Master programs of the Physics Department and the Materials Science and Technology Department of Univ. of Crete (spring semesters 2002-2018, fall semester 2019).

-Course on “*Optoelectronics and Laser*” in the 4th year of the undergraduate program of the Materials Science and Technology Department of Univ. of Crete (spring semester 2007-2008).

-Course on “*Optoelectronic and Photonic materials*” in the 4th year of the undergraduate program of the Materials Science and Technology, Department of Univ. of Crete (spring semester 2005 and 2006).

-Course on “*Microelectronic, Optoelectronic and Magnetic materials*” in the 2nd year of the undergraduate program of the Materials Science and Technology Department of Univ. of Crete (spring semester 2004).

-Series of lectures on “*Semiconductor Optical Properties and Laser Diodes*” in the Summer school of the Physics Department of Univ. of Crete (July 2002 and 2003).

-Co-directed the Microelectronics’ postgraduate program of the Physics Department of the Univ. of Crete (2001-2003).

-Teaching assistant in “*General Physics*” course in the undergraduate program of the Physics Department of Brown University, USA, (1985-1987).

Supervision:

Post-doctoral fellows:

5. **Siew Li Tan**, developing “*Innovative Nanowire Solar Cells*”, CEA/Grenoble, 2014-2016.

4. **Savvas Germanis**, performing “*Micro-photoluminescence characterization of transition metal dichalcogenides*”, FORTH, 2015-2016.

3. **Charalambos Katsidis**, on “*Simulations of semiconductor nanostructures and devices*”, University of Crete, 2013-2015.

2. **Fotis Kalaitzakis**, developing and characterizing “*Polaritonic light emitting devices in the GaAs and GaN systems*”, University of Crete/FORTH, 2012-2015.

1. **Moira Hocevar**, characterizing “*III-V Nanowires for Next Generation Photovoltaics*”, CEA/Grenoble, 2012-2013.

Ph.D thesis advisor:

13. **C. Saitanidou**, on “*GaN polariton structures as sources of entangled photons*”, Materials Science, University of Crete (9/2020-).

12. **E. Manidakis**, on “*Innovative semiconductor double-junction photovoltaic devices*”, Materials Science, University of Crete (10/2018-).

11. **N. Chatzarakis**, on “*Single-Photon and Entangled-Photon Nanophotonic Sources Based on Innovative Semiconductor-Nanostructures*”, Materials Science, University of Crete (9/2018-).

10. **E. Amargianitakis**, on “*Nitride polariton lasers*”, Materials Science, University of Crete (4/2016-12/2020).

9. **G. Dialynas**, on “*Experimental and theoretical investigation of structural and optical properties of InAs quantum dots grown on (211)GaAs substrate*”, Physics, University of Crete (2004-2020, including a 10 year long interruption of studies due to employment in secondary education).
8. **S. Germanis**, on “*Photonic devices based on piezoelectric InAs quantum dots*”, Materials Science, University of Crete (12/2010-10/2015). Subsequently, post-doc at the Pierre et Marie Curie University in Paris, developing quantum emitters based on dark states and quantum dot molecules.
7. **R. Jayaprakash**, on “*Novel approaches for robust polaritonics*”, Materials Science, University of Crete (1/2011-10/2015). Subsequently, post-doc at the Department of Physics & Astronomy of University of Sheffield, developing hybrid polaritonic devices.
6. **F. Kalaitzakis**, on “*Development of technology for improved nitride based optoelectronic devices*”, Materials Science, University of Crete (2004-2011). Subsequently, post-doc at the Microelectronics Research Group (FORTH/IESL) developing nitride-based optoelectronic devices.
5. **S. Tsintzos**, on “*Polariton light emitting devices*”, Materials Science, University of Crete (2006-2010). Subsequently, post-doc at the Microelectronics Research Group (FORTH/IESL) developing polaritonic devices.
4. **G. Deligeorgis**, on “*Laser diodes with a variable internal electric field*”, Physics, University of Crete (2002-2008). Subsequently, post-doc at the Microelectronics Research Group (FORTH/IESL) developing e-beam nano-patterning technology, and at LAAS-Toulouse developing graphene-based electronics.
3. **N. Le Thomas**, on “*Diodes laser accordables en longueur d’onde à base de l’effet Stark quantique*”, Physics, Institut Polytechnique de Grenoble (1999-2002). Subsequently, post-doc at the group of U. Woggon in Univ. of Duisburg, and of Prof. Illegems in EPFL Lausanne.
2. **J. Simon**, on “*Etude des propriétés optiques de nanostructures quantiques à base de nitrures d’éléments III*”, Physics, Université J. Fourier-Grenoble I (1998-2001). Subsequently hired by LETI in CEA/Grenoble.
1. **V. Ortiz**, on “*Etude de dispositifs optoélectroniques à base d’hétérostructures piézoélectriques*”, Physics, Université J. Fourier-Grenoble I (1996-1999). Subsequently hired at THALES Research Center.

M.Sc thesis advisor:

12. **C. Saitanidou**, on “*Towards two-dimensional GaN*”, Physics, University of Crete (2019-2020).
11. **E. Darivianaki**, on «*Hybrid nanowire/perovskite solar cells*», Materials Science, University of Crete (2018-2019).
10. **E. Manidakis**, on “*Nanowire core-shell heterostructures for photovoltaic applications*”, Materials Science, University of Crete (2017-2018).
9. **F. Miziou**, on “*Nitride microcavities for polariton devices*”, Physics, University of Crete (2016-2018).
8. **G. Thyris**, on «*Development of high temperature single photon emitters based on InAs piezoelectric quantum dots*», Physics, University of Crete (2016-2017).
7. **E. Amargianitakis**, on “*Nitride polariton structures with improved characteristics*”, Physics, University of Crete (2014-2016).
6. **S. Eftichis**, on “*Improved electrical injection of GaAs polaritonic devices*”, Physics, University of Crete (2010-2011).
5. **S. Germanis**, on “*Polarization-resolved single dot spectroscopy of (211)B InAs single quantum dots*”, Physics, University of Crete (2009-2010).
4. **S. Tsintzos**, on “*Tunable vertical-cavity surface emitting lasers*”, Physics, University of Crete (2004-2006).
3. **G. Dialynas**, on «*Influence of piezoelectric field in the lasing characteristics of InGaAs/AlGaAs quantum wells*», Physics, University of Crete (2002-2004).
2. **F. Kalaitzakis**, on “*Fabrication and optical characterisation of laser structures with InAlGaN/GaN quantum wells in the active region*”, Physics, University of Crete (2001-2003).
1. **J. Simon**, on “*Observation par spectroscopie des effets piézo-électriques géants d’hétérostructures à base de Nitrure de Gallium*”, Physics, Université J. Fourier-Grenoble I (1998).

B.Sc diploma work advisor:

3. **E. Darivianaki**, on «*Core-shell GaAs/InGaAs nanowire-based photovoltaic devices*», Materials Science, University of Crete (2017).

2. **N. Vasilantonakis**, on «*Optical characterisation of InGaAs/AlGaAs quantum wells for use in polaritonic devices*», Materials Science, University of Crete (2009).

1. **A. Pantazis**, on «*Study of InAs quantum dots self-assembled on GaAs*», Physics, University of Crete (2002).

CONFERENCE ORGANIZING:

-International Program Committee of the 34th International Conference of the Physics of Semiconductors, held in Montpellier, France, July 2018.

-Chairman of the 30th Panhellenic Conference on Solid State Physics and Materials Science, held in Heraklion Crete, September 2014. (<http://fsk30.materials.uoc.gr/>)

-Organizing and Program Committee of the Micro & Nano 2012 Conference, held in Heraklion, Kokkini Hani, October 2012.

-International Scientific Committee of the Micro & Nano 2010 Conference, held in Athens, December 2010.

-International Scientific Committee of the ICO-Photonics-Delphi2009 Conference on “Emerging Trends and Novel Materials in Photonics” in Delphi, Greece, October 7-9, 2009.

-Co-chairman of the European Workshop on III-Nitrides Semiconductors and Devices (EW3NS), held in Hersonissos Crete, September 2006.

-Programme Committee of the Microelectronics Microsystems and Nanotechnology Conference (MMN'04), held in Athens, November 2004.

-Organizing committee of the 13th Heterostructure Technology Workshop, held in Koutouloufari Crete, October 2004.

-Organizing committee of the XVIII Panhellenic Conference of Solid State Physics, held in Heraklion Crete, September 2002.

EVALUATION EXPERT:

-External Evaluator in multiple EC-funded projects (2006-2015), such as for instance in Integrated project ZODIAC on quantum dot lasers.

-Evaluation Expert for EC-proposals such as SEE-Eranet 2007, IST-2.5.1 “Photonic Components” 2005, IST-FET 2005, INTAS 2004 and 2003. Also, evaluated proposals for French (ANR) and Israeli (ISF) funding agencies.

-Reviewer/evaluator in several Greek-funded projects/proposals, such as for instance 2019 Metadidaktories, 2018 IKY, and 2017 ΕΔΒΜ34.

REVIEWING:

-Referee for Phys. Rev. Lett., Scientific Reports, ACS Photonics, Phys. Rev. B, Phys. Rev. Applied, Appl. Phys. Lett., J. Appl. Phys, phys. Stat. sol., Nanoscale Research Letters, Microelectronic Engineering.

OTHER:

-Ph.D defense committee of **Perrakis Georgios**, University of Crete, April 2021, with thesis title: “Photonic approaches for the thermal control of photovoltaics”.

-Ph.D defense committee of **Demeridou Ioanna**, University of Crete, March 2021, with thesis title: “Pulsed Laser Induced Doping of Two-Dimensional Crystals”.

-Ph.D defense committee of **Florini Nikoletta**, Aristotelian University of Thessaloniki, January 2021, with thesis title: “Study of structure and mechanical behavior of low-dimensional III-V semiconductor heterostructures”.

-Ph.D defense committee of **Doundoulakis George**, University of Crete, November 2019, with thesis title: “Realization and physical analysis of field-effect transistors based on GaN nanofins and vertical nanowires”.

- Ph.D defense committee of **Gagaoudakis Emmanuel**, University of Crete, November 2019, with thesis title: “Study of thermo-chromic materials with low growth temperature based on the vanadium oxide (VO₂)”.
- Ph.D advisory committee of **Paschos Ioannis**, University of Crete, April 2019, with thesis title: “Development of prototype polaritonic devices exploiting the macroscopic bosonic properties of polaritons in semiconductor microcavities”.
- Ph.D defense committee of **Tzimis Alexandros**, University of Crete, March 2019, with thesis title: “Study of parabolic quantum well microcavities and terahertz time domain spectroscopy in the bosonic cascade regime”.
- Ph.D defense committee of **Savvas Eftychis**, University of Crete, December 2018, with thesis title: “Spontaneous and selective growth of GaN nanowires on Si (111) substrates by molecular beam epitaxy”.
- Ph.D defense committee of **Kyriaki Savva**, University of Crete, July 2018, with thesis title: “Laser assisted development of Graphene and Transition Metal Dichalcogenide nanomaterials”.
- Ph.D defense committee of **George Kakavelakis**, University of Crete, May 2018, with thesis title: “Advanced interface engineering for solution-processable photovoltaics”.
- Ph.D defense committee of **Ioannis Paradisanos**, University of Crete, March 2018, with thesis title: “Excitons in atomically thin tungsten disulfide (WS₂) layers”.
- Ph.D defense committee of **Elena Papadomanolaki**, University of Crete, September 2017, with thesis title: “Epitaxial growth and characterization of III-nitride thin films and heterostructures for photovoltaic applications”.
- Ph.D defense committee of **Panagiotis Tsotsis**, University of Crete, February 2015, with thesis title: “Fabrication and Study of Novel Polaritonic Devices”.
- Rapporteur in the Ph.D defense committee of **Thanh Giang Le Thuy**, Université de Grenoble, July 2014, with thesis title: “Croissance de nanofils III-V par epitaxie par jets moléculaires”.
- Rapporteur in the Ph.D defense committee of **Aparna Das**, Université de Grenoble, June 2012, with thesis title: “Boîtes quantiques de semi-conducteurs nitrures pour des applications aux capteurs opto-chimiques”.
- Ph.D advisory committee of **E. Trichas**, University of Crete, December 2010, with thesis title: “Strong light-matter coupling in GaN microcavities”.
- Ph.D advisory committee of **N. Sofikiti**, University of Crete, December 2009, with thesis title: “Development of chemical sensors and biosensors based on III-nitride heterostructures and nanostructures”.
- Ph.D advisory committee of **Z. Viskadourakis**, University of Crete, June 2009, with thesis title: “Metal Oxides for Magnetotransport and Thermoelectric Applications”.
- Ph.D advisory committee of **E. Dimakis**, University of Crete, January 2007, with thesis title: “Physical mechanisms of molecular beam epitaxy and properties of InN thin films (0001)”.
- Ph.D defense committee of **Stephanie Blanc**, Université Paul Sabatier in Toulouse, November 2002, with thesis title: “Matériaux III-V épitaxiés sur substrats GaAs (111) pour structures lasers émettant au delà du micromètre”.
- Interview for an article appeared in the July 2002 issue of **Compound Semiconductors** regarding the FORTH activity on Quaternary Nitride Low-Threshold Lasers.
- Interview for an article in **Physics World** (May 2008) regarding the demonstration of a near room temperature GaAs polariton light emitting device.